## nexperia

## **Quarterly Reliability Monitoring Results**

Quarters: Q1/2021 to Q4/2021

Based on s	structural	similarity	
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Supplier		User Part Number						
Nexperia B.V.		PCMF3USB30						
Name of Laboratory		Part Description						
		NXP ICN8	Protection INI	DI				
Assembly reliability labs		WLCSP package						
Test		Test Conditions	Duration	# Lots	# Quantity	# Rejects		
	<b>TEST</b> Pre- and Post-Stress							
# 1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below		
		MIL-STD-750-1 M1038 Method A Tj = Tjmax, Vr = 100% of max. datasheet						
# 5	Bias	reverse voltage	1000 hours	43	3440	0		
# 7	<b>TC</b> Temperature Cycling	JESD22-A104 -40 °C to 125°C	1000 cycles	16	1280	0		
# 8	<b>AC</b> Autoclave	JESD22-A102 Tamb = 121 °C, RH = 100 % Pressure = 205 kPa (29.7 psia)	96 hours	n.a.	n.a.	n.a.		
# 9	<b>HAST</b> Highly Accelerated Stress Test	JESD22-A110 Tamb = 130 °C, RH = 85%, VR = 80 % of rated reverse voltage <sup>[1]</sup>	1000 hours	16	1280	0		
# 10	<b>IOL</b> Intermittent Operating Life	MIL-STD-750 Method 1037 ton = toff, devices powered to insure $\Delta Tj$ = 100 °C for 15000 cycles	1000 hours	n.a.	n.a.	n.a.		
# 20	<b>RSH</b> Resistance to Solder Heat	JESD22-A111 260 °C ± 5 °C	10 c					
# 20		200 C ± 5 C	10 s	n.a.	n.a.	n.a.		
# 21	<b>SD</b> Solderability	J-STD-002		n.a.	n.a.	n.a.		

[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

## **Calculation of FIT and MTTF**

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test # 5)

Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
NXP ICN8	Protection INDI	3440	0	1.2	8.10E+08

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